



3mm Silicon PIN Photodiode

MODEL NO : PD234-6C

■ Features :

- Fast response time
- High photo sensitivity
- Small junction capacitance
- Suitable for visible and near infrared radiation

■ Description :

PD234-6C is a high speed and high sensitive PIN photodiode in a standard 3 ϕ plastic package. The device is spectrally matched to infrared emitting diode.

■ Applications :

- High speed photo detector
- Camera
- Infrared remote controller for TVs VCR, audio equipment, air conditioner, etc.
- Game machine

PART NO.	CHIP	LENS COLOR
	MATERIAL	
PD	Silicon	Water Clear



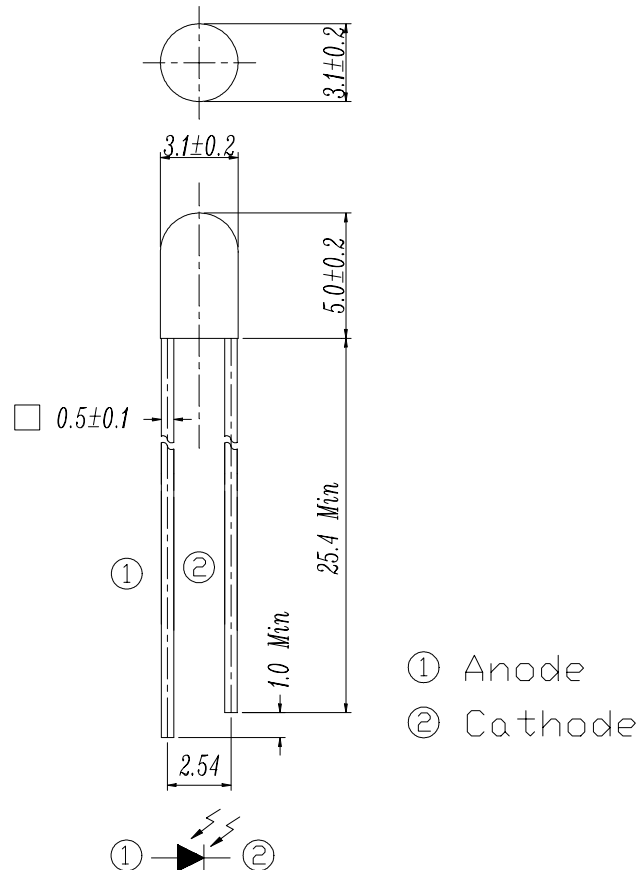
DEVICE NUMBER : DPD-023-065
ECN :

REV : 1.0
PAGE : 2/7

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■ Package Dimensions :



■ Notes :

- 1.All dimensions are in millimeter.
- 2.Protruded resin under flange 1.5 mm Max.
- 3.Lead spacing is measured where the lead emerge from the package.
- 4.Lens color : Water Clear.
- 5.Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
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- 7.When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.



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■ Absolute Maximum Ratings at T_A = 25°C

Parameter	Symbol	Rating	Unit	Notice
Reverse Voltage	V _R	32	V	
Power Dissipation	P _d	150	mW	
Lead Soldering Temperature	T _{sol}	260	°C	4mm from mold body less than 5 seconds
Operating Temperature	T _{opr}	-25 ~ +85	°C	
Storage Temperature	T _{stg}	-55 ~ +100	°C	

■ Electronic Optical Characteristics :

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Rang of Spectral Bandwidth	$\lambda_{0.5}$	----	400-1200	----	nm	-----
Wavelength of Peak Sensitivity	λ_p	----	980	----	nm	-----
Open-Circuit Voltage	V _{OC}	----	0.42	----	V	E _e =5m W/c m ² λ _p =940nm
Short-Circuit Current	I _{SC}	----	10	----	μA	
Reverse Light Current	I _L	----	10	----	μA	E _e =5m W/c m ² λ _p =940nm V _R =5V
Dark Current	I _d	----	----	10	nA	E _e =0m W/c m ² V _R =10V
Reverse Breakdown Voltage	BV _R	32	170	----	V	E _e =0m W/c m ² I _R =100μA
Total Capacitance	C _t	----	5	----	pF	E _e =0m W/c m ² V _R =5V, f=1MHz
Rise/Fall Time	t _r /t _f	----	6/6	----	nS	V _R =10V R _L =1KΩ



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■ Typical Electrical/Optical/Characteristics Curves

Fig. 1 Power Dissipation vs. Ambient Temperature

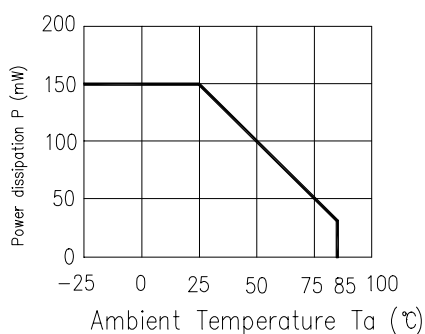


Fig.2 Spectral Sensitivity

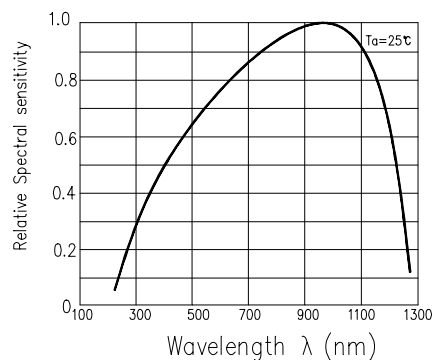


Fig.3 Dark Current vs. Ambient Temperature

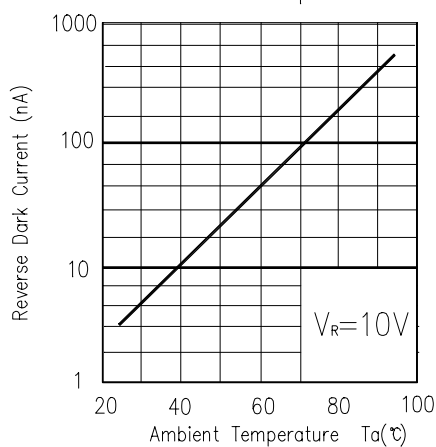


Fig.4 Reverse Light Current vs.Ee

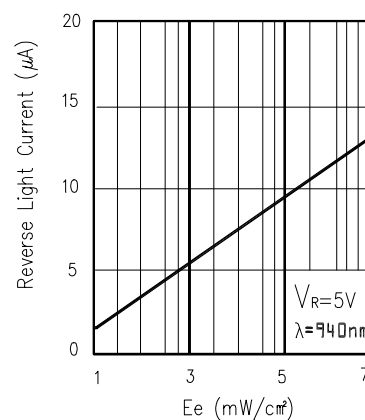


Fig.5 Terminal Capacitance vs. Reverse Voltage

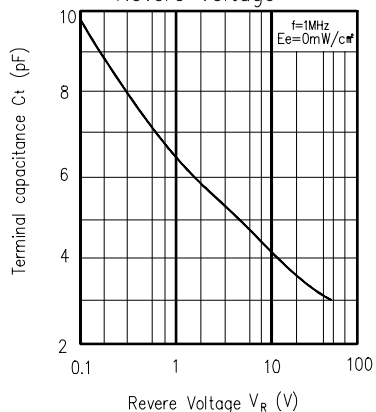
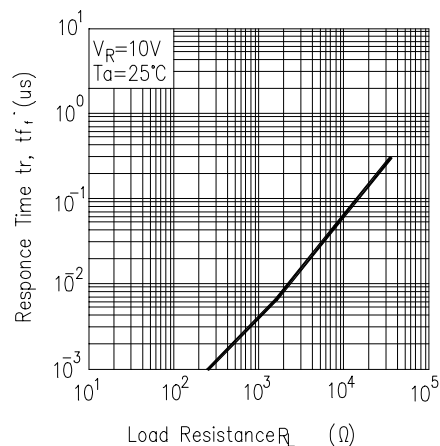


Fig.6 Response Time vs. Load Resistance





DEVICE NUMBER : DPD-023-065
ECN :

REV : 1.0
PAGE : 6/7

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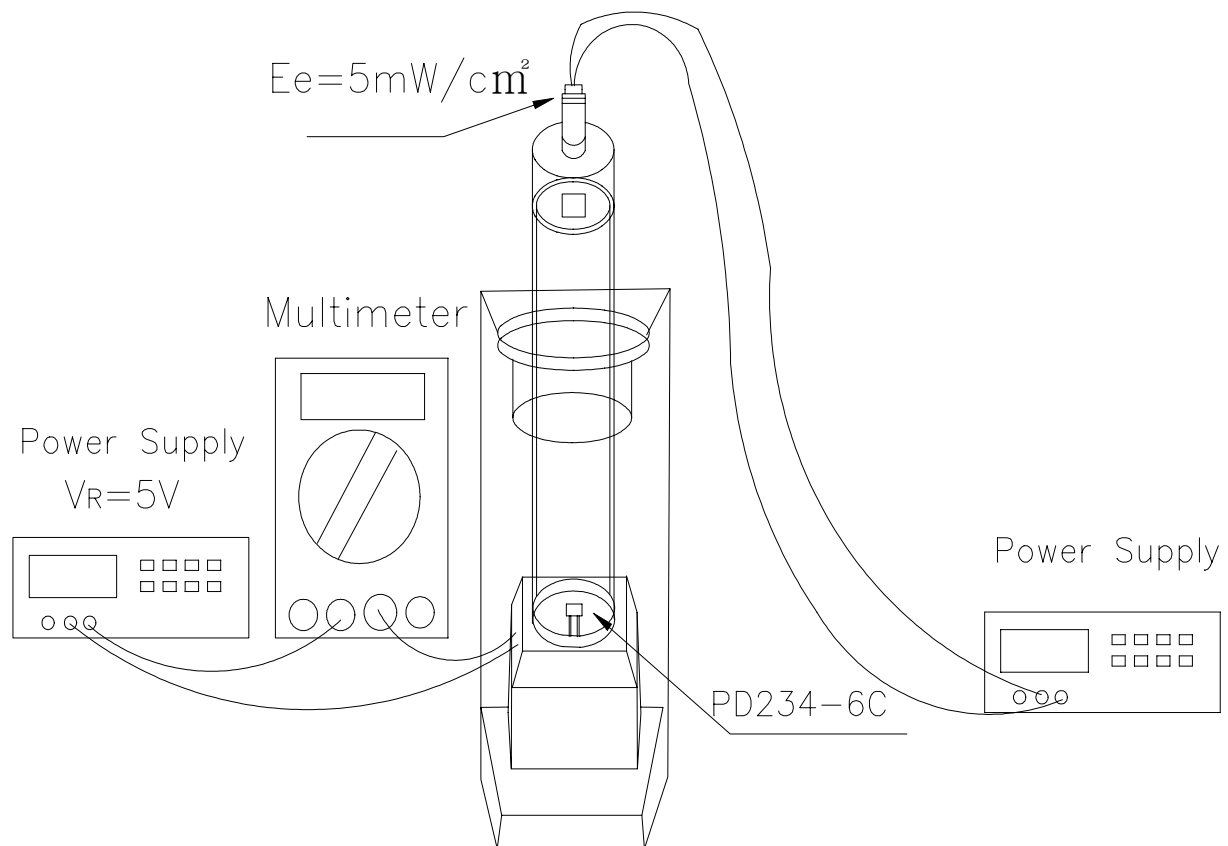
MODEL NO : PD234-6C

■ Test Method For Reverse Light Current

Condition: $E_e=5\text{mW}/\text{cm}^2$, $V_R=5\text{V}$

Test Item: Reverse Light Current

Unit : μA





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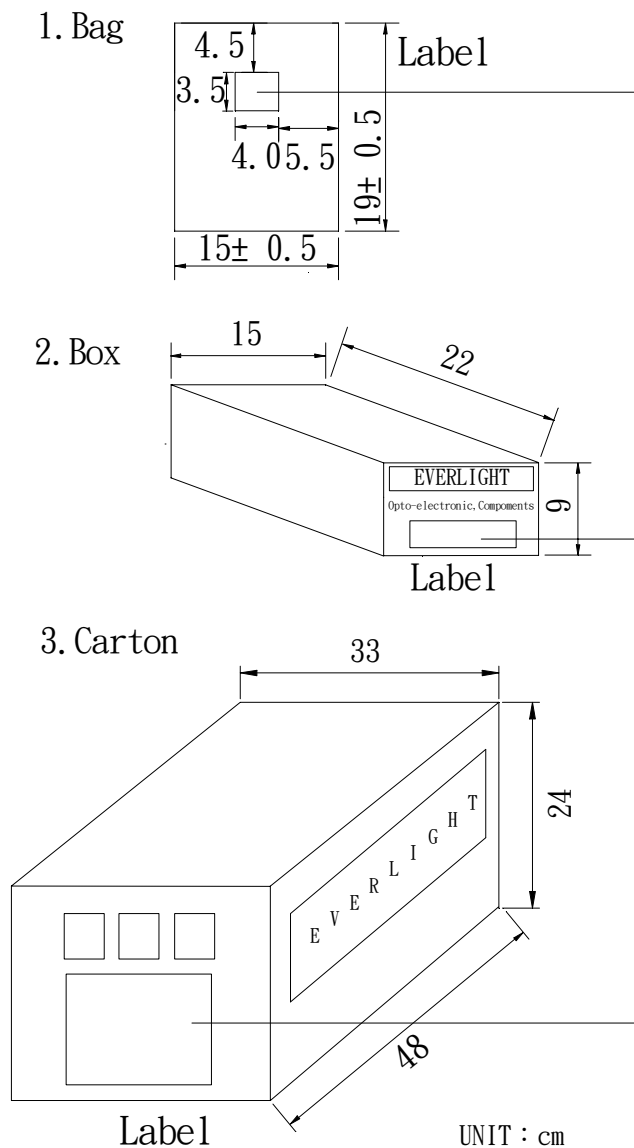
DEVICE NUMBER : DPD-023-065
ECN :

REV : 1.0
PAGE : 7/7

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■ Packing Specifications



EVERLIGHT

CPN:

P/N:

PD234-6C

QTY:

LOT NO:

CAT:

HUE:

REF:

MADE IN TAIWAN

CPN : Customer's Production Number

P/N : Production Number

QTY : Packing Quantity

CAT : Ranks

HUE : Peak Wavelength

REF : Reference

LOT NO : Lot Number

MADE IN TAIWAN : Production place

■ Packing Quantity Specification

1. 1000 Pcs/1Bag , 4 Bags/1Box
2. 10 Boxes/1Carton